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Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

Details

Product Status	Active
Core Processor	PIC
Core Size	8-Bit
Speed	4MHz
Connectivity	-
Peripherals	POR, WDT
Number of I/O	20
Program Memory Size	3KB (2K x 12)
Program Memory Type	OTP
EEPROM Size	-
RAM Size	72 x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 6.25V
Data Converters	-
Oscillator Type	External
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	28-SOIC (0.295", 7.50mm Width)
Supplier Device Package	28-SOIC
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/pic16c57t-xti-so

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

4.4 RC Oscillator

For timing insensitive applications, the RC device option offers additional cost savings. The RC oscillator frequency is a function of the supply voltage, the resistor (REXT) and capacitor (CEXT) values, and the operating temperature. In addition to this, the oscillator frequency will vary from unit to unit due to normal process parameter variation. Furthermore, the difference in lead frame capacitance between package types will also affect the oscillation frequency, especially for low CEXT values. The user also needs to take into account variation due to tolerance of external R and C components used.

Figure 4-5 shows how the R/C combination is connected to the PIC16C5X. For REXT values below 2.2 k Ω , the oscillator operation may become unstable, or stop completely. For very high REXT values (e.g., 1 M Ω) the oscillator becomes sensitive to noise, humidity and leakage. Thus, we recommend keeping REXT between 3 k Ω and 100 k Ω .

Although the oscillator will operate with no external capacitor (CEXT = 0 pF), we recommend using values above 20 pF for noise and stability reasons. With no or small external capacitance, the oscillation frequency can vary dramatically due to changes in external capacitances, such as PCB trace capacitance or package lead frame capacitance.

The Electrical Specifications sections show RC frequency variation from part to part due to normal process variation. The variation is larger for larger R (since leakage current variation will affect RC frequency more for large R) and for smaller C (since variation of input capacitance will affect RC frequency more).

Also, see the Electrical Specifications sections for variation of oscillator frequency due to VDD for given REXT/ CEXT values as well as frequency variation due to operating temperature for given R, C, and VDD values.

The oscillator frequency, divided by 4, is available on the OSC2/CLKOUT pin, and can be used for test purposes or to synchronize other logic.



Note: If you change from this device to another device, please verify oscillator characteristics in your application.

5.1 Power-On Reset (POR)

The PIC16C5X family incorporates on-chip Power-On Reset (POR) circuitry which provides an internal chip RESET for most power-up situations. To use this feature, the user merely ties the MCLR/VPP pin to VDD. A simplified block diagram of the on-chip Power-On Reset circuit is shown in Figure 5-1.

The Power-On Reset circuit and the Device Reset Timer (Section 5.2) circuit are closely related. On power-up, the RESET latch is set and the DRT is <u>RESET</u>. The DRT timer begins counting once it detects MCLR to be high. After the time-out period, which is typically 18 ms, it will RESET the reset latch and thus end the on-chip RESET signal.

A power-up example where MCLR is not tied to VDD is shown in Figure 5-3. VDD is allowed to rise and stabilize before bringing MCLR high. The chip will actually come out of reset TDRT msec after MCLR goes high.

In Figure 5-4, the on-chip Power-On Reset feature is being used (MCLR and VDD are tied together). The VDD is stable before the start-up timer times out and there is no problem in getting a proper RESET. However, Figure 5-5 depicts a problem situation where VDD rises too slowly. The time between when the DRT senses a high on the MCLR/VPP pin, and when the MCLR/VPP pin (and VDD) actually reach their full value, is too long. In this situation, when the start-up timer times out, VDD has not reached the VDD (min) value and the chip is, therefore, not guaranteed to function correctly. For such situations, we recommend that external RC circuits be used to achieve longer POR delay times (Figure 5-2).

Note: When the device starts normal operation (exits the RESET condition), device operating parameters (voltage, frequency, temperature, etc.) must be met to ensure operation. If these conditions are not met, the device must be held in RESET until the operating conditions are met.

For more information on PIC16C5X POR, see *Power-Up Considerations* - AN522 in the <u>Embedded Control Handbook</u>.

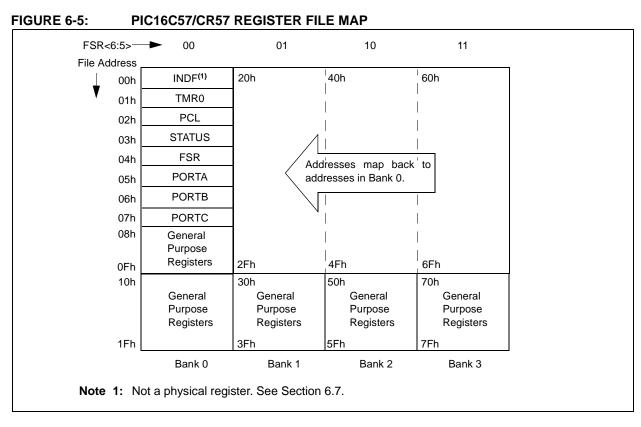
The POR circuit does not produce an internal RESET when VDD declines.

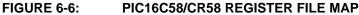
FIGURE 5-2:

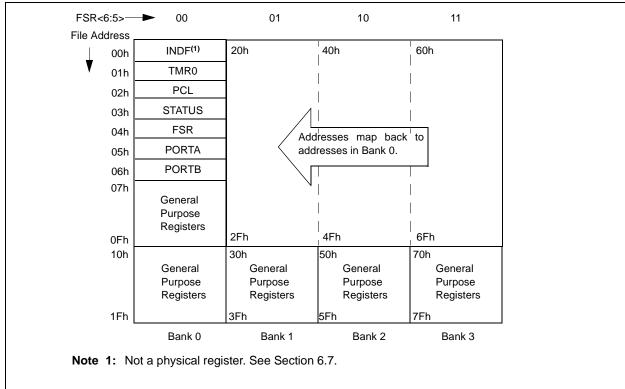
EXTERNAL POWER-ON RESET CIRCUIT (FOR SLOW VDD POWER-UP)



- External Power-On Reset circuit is required only if VDD power-up is too slow. The diode D helps discharge the capacitor quickly when VDD powers down.
- R < 40 kΩ is recommended to make sure that voltage drop across R does not violate the device electrical specification.
- R1 = 100Ω to 1 k Ω will limit any current flowing into \overline{MCLR} from external capacitor C in the event of \overline{MCLR} pin breakdown due to Electrostatic Discharge (ESD) or Electrical Overstress (EOS).







6.5.1 PAGING CONSIDERATIONS – PIC16C56/CR56, PIC16C57/CR57 AND PIC16C58/CR58

If the Program Counter is pointing to the last address of a selected memory page, when it increments it will cause the program to continue in the next higher page. However, the page preselect bits in the STATUS Register will not be updated. Therefore, the next GOTO, CALL or modify PCL instruction will send the program to the page specified by the page preselect bits (PA0 or PA<1:0>).

For example, a NOP at location 1FFh (page 0) increments the PC to 200h (page 1). A GOTO xxx at 200h will return the program to address xxh on page 0 (assuming that PA<1:0> are clear).

To prevent this, the page preselect bits must be updated under program control.

6.5.2 EFFECTS OF RESET

The Program Counter is set upon a RESET, which means that the PC addresses the last location in the last page (i.e., the RESET vector).

The STATUS Register page preselect bits are cleared upon a RESET, which means that page 0 is pre-selected.

Therefore, upon a RESET, a GOTO instruction at the RESET vector location will automatically cause the program to jump to page 0.

6.6 Stack

PIC16C5X devices have a 10-bit or 11-bit wide, two-level hardware push/pop stack.

A CALL instruction will push the current value of stack 1 into stack 2 and then push the current program counter value, incremented by one, into stack level 1. If more than two sequential CALL's are executed, only the most recent two return addresses are stored.

A RETLW instruction will pop the contents of stack level 1 into the program counter and then copy stack level 2 contents into level 1. If more than two sequential RETLW's are executed, the stack will be filled with the address previously stored in level 2. Note that the W Register will be loaded with the literal value specified in the instruction. This is particularly useful for the implementation of data look-up tables within the program memory.

For the RETLW instruction, the PC is loaded with the Top of Stack (TOS) contents. All of the devices covered in this data sheet have a two-level stack. The stack has the same bit width as the device PC, therefore, paging is not an issue when returning from a subroutine. NOTES:

7.0 I/O PORTS

As with any other register, the I/O Registers can be written and read under program control. However, read instructions (e.g., MOVF PORTB, W) always read the I/O pins independent of the pin's input/output modes. On RESET, all I/O ports are defined as input (inputs are at hi-impedance) since the I/O control registers (TRISA, TRISB, TRISC) are all set.

7.1 PORTA

PORTA is a 4-bit I/O Register. Only the low order 4 bits are used (RA<3:0>). Bits 7-4 are unimplemented and read as '0's.

7.2 PORTB

PORTB is an 8-bit I/O Register (PORTB<7:0>).

7.3 PORTC

PORTC is an 8-bit I/O Register for PIC16C55, PIC16C57 and PIC16CR57.

PORTC is a General Purpose Register for PIC16C54, PIC16CR54, PIC16CR56, PIC16CR56, PIC16CS8 and PIC16CR58.

7.4 TRIS Registers

The Output Driver Control Registers are loaded with the contents of the W Register by executing the TRIS f instruction. A '1' from a TRIS Register bit puts the corresponding output driver in a hi-impedance (input) mode. A '0' puts the contents of the output data latch on the selected pins, enabling the output buffer.

Note:	A read of the ports reads the pins, not the
	output data latches. That is, if an output
	driver on a pin is enabled and driven high,
	but the external system is holding it low, a
	read of the port will indicate that the pin is
	low.

The TRIS Registers are "write-only" and are set (output drivers disabled) upon RESET.

TABLE 7-1:	SUMMARY OF PORT REGISTERS

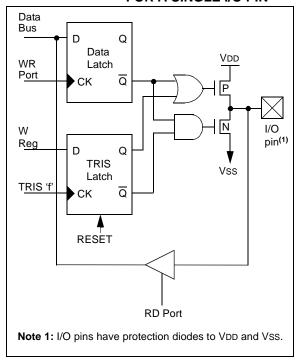
Value on Value on Bit 4 Bit 3 Bit 1 Bit 0 MCLR and Address Name Bit 7 Bit 6 Bit 5 Bit 2 Power-On Reset WDT Reset TRIS N/A I/O Control Registers (TRISA, TRISB, TRISC) 1111 1111 1111 1111 05h PORTA RA3 RA2 RA1 RA0 _ _ _ _ xxxx _ _ _ _ uuuu PORTB 06h RB7 RB6 RB5 RB4 RB3 RB2 RB1 RB0 XXXX XXXX uuuu uuuu 07h PORTC RC7 RC6 RC5 RC4 RC3 RC2 RC1 RC0 XXXX XXXX uuuu uuuu

Legend: x = unknown, u = unchanged, - = unimplemented, read as '0', Shaded cells = unimplemented, read as '0'

7.5 I/O Interfacing

The equivalent circuit for an I/O port pin is shown in Figure 7-1. All ports may be used for both input and output operation. For input operations these ports are non-latching. Any input must be present until read by an input instruction (e.g., MOVF PORTB, W). The outputs are latched and remain unchanged until the output latch is rewritten. To use a port pin as output, the corresponding direction control bit (in TRISA, TRISB, TRISC) must be cleared (= 0). For use as an input, the corresponding TRIS bit must be set. Any I/O pin can be programmed individually as input or output.

FIGURE 7-1: EQUIVALENT CIRCUIT FOR A SINGLE I/O PIN



8.2 Prescaler

An 8-bit counter is available as a prescaler for the Timer0 module, or as a postscaler for the Watchdog Timer (WDT), respectively (Section 9.2.1). For simplicity, this counter is being referred to as "prescaler" throughout this data sheet. Note that the prescaler may be used by either the Timer0 module or the WDT, but not both. Thus, a prescaler assignment for the Timer0 module means that there is no prescaler for the WDT, and vice-versa.

The PSA and PS<2:0> bits (OPTION<3:0>) determine prescaler assignment and prescale ratio.

When assigned to the Timer0 module, all instructions writing to the TMR0 register (e.g., CLRF 1, MOVWF 1, BSF 1, x, etc.) will clear the prescaler. When assigned to WDT, a CLRWDT instruction will clear the prescaler along with the WDT. The prescaler is neither readable nor writable. On a RESET, the prescaler contains all '0's.

8.2.1 SWITCHING PRESCALER ASSIGNMENT

The prescaler assignment is fully under software control (i.e., it can be changed "on the fly" during program execution). To avoid an unintended device RESET, the following instruction sequence (Example 8-1) must be executed when changing the prescaler assignment from Timer0 to the WDT.

EXAMPLE 8-1: CHANGING PRESCALER (TIMER0→WDT)

CLRWDT	;Clear WDT
CLRF TMR0	Clear TMR0 & Prescaler
MOVLW B'00xx1111'	;Last 3 instructions in
	this example
OPTION	;are required only if
	;desired
CLRWDT	;PS<2:0> are 000 or
	;001
MOVLW B'00xx1xxx'	;Set Prescaler to
OPTION	;desired WDT rate

To change prescaler from the WDT to the Timer0 module, use the sequence shown in Example 8-2. This sequence must be used even if the WDT is disabled. A CLRWDT instruction should be executed before switching the prescaler.

EXAMPLE 8-2: CHANGING PRESCALER (WDT \rightarrow TIMER0)

CLRWDT		;Clear WDT and
		;prescaler
MOVLW	B'xxxx0xxx'	;Select TMR0, new
		;prescale value and
		;clock source

OPTION

9.3 Power-Down Mode (SLEEP)

A device may be powered down (SLEEP) and later powered up (Wake-up from SLEEP).

9.3.1 SLEEP

The Power-down mode is entered by executing a SLEEP instruction.

If enabled, the Watchdog Timer will be cleared but keeps running, the TO bit (STATUS<4>) is set, the PD bit (STATUS<3>) is cleared and the oscillator driver is turned off. The I/O ports maintain the status they had before the SLEEP instruction was executed (driving high, driving low, or hi-impedance).

It should be noted that a RESET generated by a WDT time-out does not drive the MCLR/VPP pin low.

For lowest current consumption while powered down, the T0CKI input should be at VDD or Vss and the $\overline{\text{MCLR}}/\text{VPP}$ pin must be at a logic high level ($\overline{\text{MCLR}} = \text{VIH}$).

9.3.2 WAKE-UP FROM SLEEP

The device can wake up from SLEEP through one of the following events:

- 1. An external RESET input on MCLR/VPP pin.
- 2. A Watchdog Timer Time-out Reset (if WDT was enabled).

Both of these events cause a device RESET. The $\overline{\text{TO}}$ and $\overline{\text{PD}}$ bits can be used to determine the cause of device RESET. The $\overline{\text{TO}}$ bit is cleared if a WDT timeout occurred (and caused wake-up). The $\overline{\text{PD}}$ bit, which is set on power-up, is cleared when SLEEP is invoked.

The WDT is cleared when the device wakes from SLEEP, regardless of the wake-up source.

9.4 Program Verification/Code Protection

If the code protection bit(s) have not been programmed, the on-chip program memory can be read out for verification purposes.

Note:	Microchip does not recommend code pro-
	tecting windowed devices.

9.5 ID Locations

Four memory locations are designated as ID locations where the user can store checksum or other code-identification numbers. These locations are not accessible during normal execution but are readable and writable during program/verify.

Use only the lower 4 bits of the ID locations and always program the upper 8 bits as '1's.

Note: Microchip will assign a unique pattern number for QTP and SQTP requests and for ROM devices. This pattern number will be unique and traceable to the submitted code.

Mnemonic,		Description	Cualaa	12-1	Bit Opc	Status		
Opera	nds	Description	Cycles	MSb		LSb	Affected	Notes
ADDWF	f,d	Add W and f	1	0001	11df	ffff	C,DC,Z	1,2,4
ANDWF	f,d	AND W with f	1	0001	01df	ffff	Z	2,4
CLRF	f	Clear f	1	0000	011f	ffff	Z	4
CLRW	-	Clear W	1	0000	0100	0000	Z	
COMF	f, d	Complement f	1	0010	01df	ffff	Z	
DECF	f, d	Decrement f	1	0000	11df	ffff	Z	2,4
DECFSZ	f, d	Decrement f, Skip if 0	1 ⁽²⁾	0010	11df	ffff	None	2,4
INCF	f, d	Increment f	1	0010	10df	ffff	Z	2,4
INCFSZ	f, d	Increment f, Skip if 0	1 ⁽²⁾	0011	11df	ffff	None	2,4
IORWF	f, d	Inclusive OR W with f	1	0001	00df	ffff	Z	2,4
MOVF	f, d	Move f	1	0010	00df	ffff	Z	2,4
MOVWF	f	Move W to f	1	0000	001f	ffff	None	1,4
NOP	-	No Operation	1	0000	0000	0000	None	
RLF	f, d	Rotate left f through Carry	1	0011	01df	ffff	С	2,4
RRF	f, d	Rotate right f through Carry	1	0011	00df	ffff	С	2,4
SUBWF	f, d	Subtract W from f	1	0000	10df	ffff	C,DC,Z	1,2,4
SWAPF	f, d	Swap f	1	0011	10df	ffff	None	2,4
XORWF	f, d	Exclusive OR W with f	1	0001	10df	ffff	Z	2,4
BIT-ORIEN	TED FIL	E REGISTER OPERATIONS	•					
BCF	f, b	Bit Clear f	1	0100	bbbf	ffff	None	2,4
BSF	f, b	Bit Set f	1	0101	bbbf	ffff	None	2,4
BTFSC	f, b	Bit Test f, Skip if Clear	1 (2)	0110	bbbf	ffff	None	
BTFSS	f, b	Bit Test f, Skip if Set	1 (2)	0111	bbbf	ffff	None	
LITERAL A	ND CON	ITROL OPERATIONS	•					
ANDLW	k	AND literal with W	1	1110	kkkk	kkkk	Z	
CALL	k	Call subroutine	2	1001	kkkk	kkkk	None	1
CLRWDT	k	Clear Watchdog Timer	1	0000	0000	0100	TO, PD	
GOTO	k	Unconditional branch	2	101k	kkkk	kkkk	None	
IORLW	k	Inclusive OR Literal with W	1	1101	kkkk	kkkk	Z	
MOVLW	k	Move Literal to W	1	1100	kkkk	kkkk	None	
OPTION	k	Load OPTION register	1	0000	0000	0010	None	
RETLW	k	Return, place Literal in W	2	1000	kkkk	kkkk	None	
SLEEP	_	Go into standby mode	1	0000	0000	0011	TO, PD	
TRIS	f	Load TRIS register	1	0000	0000	Offf	None	3
XORLW	k	Exclusive OR Literal to W	1	1111	kkkk	kkkk	Z	

TABLE 10-2: INSTRUCTION SET SUMMARY

Note 1: The 9th bit of the program counter will be forced to a '0' by any instruction that writes to the PC except for GOTO (see Section 6.5 for more on program counter).

2: When an I/O register is modified as a function of itself (e.g. MOVF PORTB, 1), the value used will be that value present on the pins themselves. For example, if the data latch is '1' for a pin configured as input and is driven low by an external device, the data will be written back with a '0'.

3: The instruction TRIS f, where f = 5, 6 or 7 causes the contents of the W register to be written to the tristate latches of PORTA, B or C respectively. A '1' forces the pin to a hi-impedance state and disables the output buffers.

4: If this instruction is executed on the TMR0 register (and, where applicable, d = 1), the prescaler will be cleared (if assigned to TMR0).

GOTO	Uncondi	tional B	anch				
Syntax:	[label]	GOTO	k				
Operands:	$0 \le k \le 511$						
Operation:	k → PC<8:0>; STATUS<6:5> → PC<10:9>						
Status Affected:	None						
Encoding:	101k	kkkk	kkkk				
Description:	GOTO is an unconditional branch. The 9-bit immediate value is loaded into PC bits <8:0>. The upper bits of PC are loaded from STATUS<6:5>. GOTO is a two- cycle instruction.						
Words:	1						
Cycles: 2							
Example: GOTO THERE							
After Instruct PC =	ion address	G (THER	E)				

INCF	Increment f					
Syntax:	[label] INCF f,d					
Operands:	$\begin{array}{l} 0 \leq f \leq 31 \\ d \in [0,1] \end{array}$					
Operation:	(f) + 1 \rightarrow (dest)					
Status Affected:	Z					
Encoding:	0010 10df ffff					
Description:	The contents of register 'f' are incremented. If 'd' is 0 the result is placed in the W register. If 'd' is 1 the result is placed back in register 'f'.					
Words:	1					
Cycles:	1					
Example:	INCF CNT, 1					
Before Instru CNT Z After Instruct CNT Z	= 0xFF = 0					

INCFSZ	Increment f, Skip if 0						
Syntax:	[label] INCFSZ f,d						
Operands:	$\begin{array}{l} 0 \leq f \leq 31 \\ d \in [0,1] \end{array}$						
Operation:	(f) + 1 \rightarrow (dest), skip if result = 0						
Status Affected:	None						
Encoding:	0011 11df ffff						
Description:	The contents of register 'f' are incremented. If 'd' is 0 the result is placed in the W register. If 'd' is 1 the result is placed back in register 'f'. If the result is 0, then the next instruction, which is already fetched, is discarded and a NOP is executed instead making it a two- cycle instruction.						
Words:	1						
Cycles:	1(2)						
Example:	HERE INCFSZ CNT, 1 GOTO LOOP CONTINUE • • •						
Before Instru PC After Instruc	= address (HERE)						
CNT if CNT PC if CNT PC	<pre>= CNT + 1; = 0, = address (CONTINUE); ≠ 0, = address (HERE +1)</pre>						

12.1 DC Characteristics: PIC16C54/55/56/57-RC, XT, 10, HS, LP (Commercial)

PIC16C54/55/56/57-RC, XT, 10, HS, LP (Commercial)		Standard Operating Conditions (unless otherwise specified Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial					
Param No.	Symbol	Characteristic/Device	Min	Тур†	Max	Units	Conditions
D001	Vdd	Supply Voltage PIC16C5X-RC PIC16C5X-XT PIC16C5X-10 PIC16C5X-HS PIC16C5X-LP	3.0 3.0 4.5 4.5 2.5		6.25 6.25 5.5 5.5 6.25	V V V V	
D002	Vdr	RAM Data Retention Voltage ⁽¹⁾	_	1.5*	_	V	Device in SLEEP Mode
D003	VPOR	VDD Start Voltage to ensure Power-on Reset		Vss	—	V	See Section 5.1 for details on Power-on Reset
D004	Svdd	VDD Rise Rate to ensure Power-on Reset	0.05*		—	V/ms	See Section 5.1 for details on Power-on Reset
D010	IDD	Supply Current ⁽²⁾ PIC16C5X-RC ⁽³⁾ PIC16C5X-XT PIC16C5X-10 PIC16C5X-HS PIC16C5X-HS PIC16C5X-LP	 	1.8 1.8 4.8 4.8 9.0 15	3.3 3.3 10 10 20 32	mA mA mA mA μA	Fosc = 4 MHz, VDD = $5.5V$ Fosc = 4 MHz, VDD = $5.5V$ Fosc = 10 MHz, VDD = $5.5V$ Fosc = 10 MHz, VDD = $5.5V$ Fosc = 20 MHz, VDD = $5.5V$ Fosc = 32 kHz, VDD = $3.0V$, WDT disabled
D020	Ipd	Power-down Current ⁽²⁾	_	4.0 0.6	12 9	μΑ μΑ	VDD = 3.0V, WDT enabled VDD = 3.0V, WDT disabled

* These parameters are characterized but not tested.

† Data in "Typ" column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.

2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.

- a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, T0CKI = VDD, MCLR = VDD; WDT enabled/disabled as specified.
- b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
- **3:** Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in k Ω .

12.2 DC Characteristics: PIC16C54/55/56/57-RCI, XTI, 10I, HSI, LPI (Industrial)

PIC16C54/55/56/57-RCI, XTI, 10I, HSI, LPI (Industrial)		Standard Operating Conditions (unless otherwise specified) Operating Temperature $-40^{\circ}C \le TA \le +85^{\circ}C$ for industrial					
Param No.	Symbol	Characteristic/Device	Min	Тур†	Max	Units	Conditions
D001	Vdd	Supply Voltage PIC16C5X-RCI PIC16C5X-XTI PIC16C5X-10I PIC16C5X-HSI PIC16C5X-LPI	3.0 3.0 4.5 4.5 2.5		6.25 6.25 5.5 5.5 6.25	V V V V	
D002	Vdr	RAM Data Retention Voltage ⁽¹⁾		1.5*		V	Device in SLEEP mode
D003	VPOR	VDD Start Voltage to ensure Power-on Reset	—	Vss	—	V	See Section 5.1 for details on Power-on Reset
D004	SVDD	VDD Rise Rate to ensure Power-on Reset	0.05*		—	V/ms	See Section 5.1 for details on Power-on Reset
D010	IDD	Supply Current ⁽²⁾ PIC16C5X-RCI ⁽³⁾ PIC16C5X-XTI PIC16C5X-10I PIC16C5X-HSI PIC16C5X-HSI PIC16C5X-LPI		1.8 1.8 4.8 4.8 9.0 15	3.3 3.3 10 10 20 40	mA mA mA mA μA	Fosc = 4 MHz, VDD = $5.5V$ Fosc = 4 MHz, VDD = $5.5V$ Fosc = 10 MHz, VDD = $5.5V$ Fosc = 10 MHz, VDD = $5.5V$ Fosc = 20 MHz, VDD = $5.5V$ Fosc = 32 kHz, VDD = $3.0V$, WDT disabled
D020	Ipd	Power-down Current ⁽²⁾	_	4.0 0.6	14 12	μΑ μΑ	VDD = 3.0V, WDT enabled VDD = 3.0V, WDT disabled

* These parameters are characterized but not tested.

- † Data in "Typ" column is based on characterization results at 25°C. This data is for design guidance only and is not tested.
- Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
 - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
 - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, T0CKI = VDD, MCLR = VDD; WDT enabled/disabled as specified.
 - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
 - **3:** Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in kΩ.

12.4 DC Characteristics: PIC16C54/55/56/57-RC, XT, 10, HS, LP (Commercial) PIC16C54/55/56/57-RCI, XTI, 10I, HSI, LPI (Industrial)

DC CHARACTERISTICS			$\begin{array}{ll} \mbox{Standard Operating Conditions (unless otherwise specified)} \\ \mbox{Operating Temperature} & 0^\circ C \leq T A \leq +70^\circ C \mbox{ for commercial} \\ -40^\circ C \leq T A \leq +85^\circ C \mbox{ for industrial} \end{array}$					
Param No.	Symbol	Characteristic/Device	Min	Тур†	Max	Units	Conditions	
D030	VIL	Input Low Voltage I/O ports MCLR (Schmitt Trigger) TOCKI (Schmitt Trigger) OSC1 (Schmitt Trigger) OSC1 (Schmitt Trigger)	Vss Vss Vss Vss Vss Vss		0.2 VDD 0.15 VDD 0.15 VDD 0.15 VDD 0.3 VDD	V V V V	Pin at hi-impedance PIC16C5X-RC only ⁽³⁾ PIC16C5X-XT, 10, HS, LP	
D040	Vih	Input High Voltage I/O ports I/O ports I/O ports MCLR (Schmitt Trigger) T0CKI (Schmitt Trigger) OSC1 (Schmitt Trigger) OSC1 (Schmitt Trigger)	0.45 VDD 2.0 0.36 VDD 0.85 VDD 0.85 VDD 0.85 VDD 0.7 VDD		VDD VDD VDD VDD VDD VDD VDD	V V V V V V	For all VDD ⁽⁴⁾ 4.0V < VDD ≤ 5.5V ⁽⁴⁾ VDD > 5.5V PIC16C5X-RC only ⁽³⁾ PIC16C5X-XT, 10, HS, LP	
D050	VHYS	Hysteresis of Schmitt Trigger inputs	0.15 Vdd*	—	—	V		
D060	Ιι∟	Input Leakage Current ^(1,2) I/O ports MCLR MCLR T0CKI OSC1	-1 -5 -3 -3	0.5 — 0.5 0.5 0.5	+1 +5 +3 +3	μΑ μΑ μΑ μΑ μΑ	For VDD \leq 5.5V: VSS \leq VPIN \leq VDD, pin at hi-impedance VPIN = VSS + 0.25V VPIN = VDD VSS \leq VPIN \leq VDD VSS \leq VPIN \leq VDD, PIC16C5X-XT, 10, HS, LP	
D080	Vol	Output Low Voltage I/O ports OSC2/CLKOUT		_	0.6 0.6	V V	IOL = 8.7 mA, VDD = 4.5V IOL = 1.6 mA, VDD = 4.5V, PIC16C5X-RC	
D090	Vон	Output High Voltage ⁽²⁾ I/O ports OSC2/CLKOUT	Vdd - 0.7 Vdd - 0.7		—	V V	IOH = -5.4 mA, VDD = 4.5V IOH = -1.0 mA, VDD = 4.5V, PIC16C5X-RC	

* These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

- **Note 1:** The leakage current on the MCLR/VPP pin is strongly dependent on the applied voltage level. The specified levels represent normal operating conditions. Higher leakage current may be measured at different input voltage.
 - 2: Negative current is defined as coming out of the pin.
 - **3:** For PIC16C5X-RC devices, the OSC1/CLKIN pin is a Schmitt Trigger input. It is not recommended that the PIC16C5X be driven with external clock in RC mode.
 - 4: The user may use the better of the two specifications.

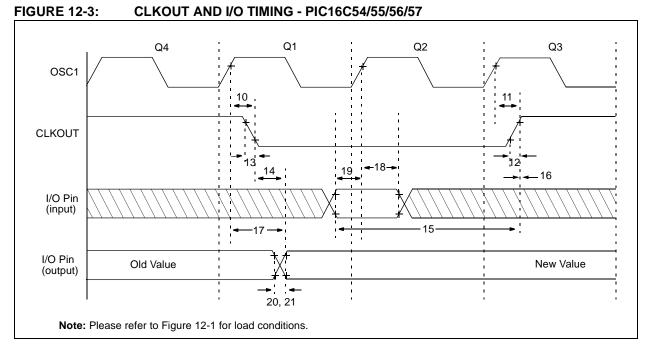


TABLE 12-2: CLKOUT AND I/O TIMING REQUIREMENTS - PIC16C54/55/56/57

AC Characteristics		$\begin{array}{llllllllllllllllllllllllllllllllllll$							
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units			
10	TosH2ckL	OSC1↑ to CLKOUT↓ ⁽¹⁾	—	15	30**	ns			
11	TosH2ckH	OSC1 [↑] to CLKOUT ^{↑(1)}	—	15	30**	ns			
12	TckR	CLKOUT rise time ⁽¹⁾	—	5.0	15**	ns			
13	TckF	CLKOUT fall time ⁽¹⁾	—	5.0	15**	ns			
14	TckL2ioV	CLKOUT↓ to Port out valid ⁽¹⁾	—	—	40**	ns			
15	TioV2ckH	Port in valid before CLKOUT ⁽¹⁾	0.25 TCY+30*		_	ns			
16	TckH2iol	Port in hold after CLKOUT ⁽¹⁾	0*	—	_	ns			
17	TosH2ioV	OSC1 [↑] (Q1 cycle) to Port out valid ⁽²⁾	—	—	100*	ns			
18	TosH2iol	OSC1 [↑] (Q2 cycle) to Port input invalid (I/O in hold time)	TBD	—	_	ns			
19	TioV2osH	Port input valid to OSC1↑ (I/O in setup time)	TBD	—	_	ns			
20	TioR	Port output rise time ⁽²⁾	—	10	25**	ns			
21	TioF	Port output fall time ⁽²⁾	_	10	25**	ns			

* These parameters are characterized but not tested.

** These parameters are design targets and are not tested. No characterization data available at this time.

† Data in the Typical ("Typ") column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: Measurements are taken in RC Mode where CLKOUT output is 4 x Tosc.

2: Please refer to Figure 12-1 for load conditions.

FIGURE 14-6: MAXIMUM IPD vs. VDD, WATCHDOG DISABLED

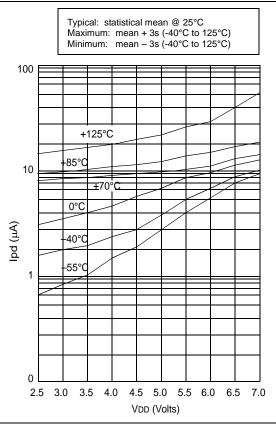


FIGURE 14-7: T

TYPICAL IPD vs. VDD, WATCHDOG ENABLED

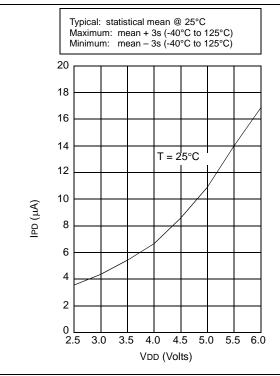
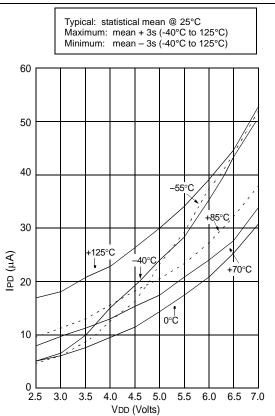
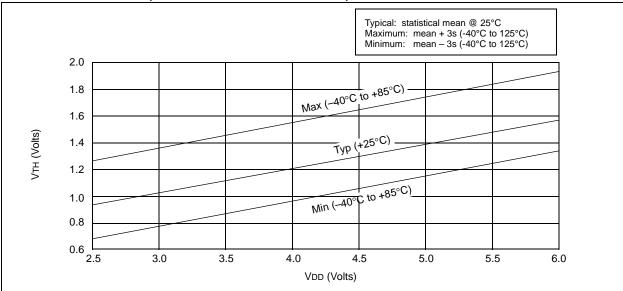


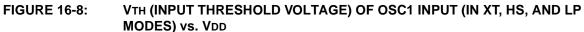
FIGURE 14-8: MAXIMUM IPD vs. VDD, WATCHDOG ENABLED

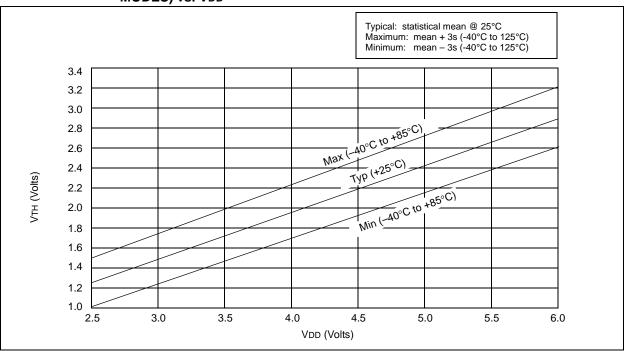


IPD, with WDT enabled, has two components: The leakage current, which increases with higher temperature, and the operating current of the WDT logic, which increases with lower temperature. At -40° C, the latter dominates explaining the apparently anomalous behavior.

FIGURE 16-7: VTH (INPUT THRESHOLD VOLTAGE) OF I/O PINS - VDD







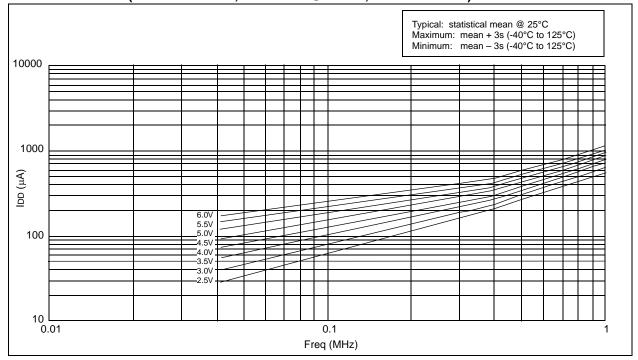
 Typical: statistical mean @ 25°C.

 Maximum: mean + 3s (-40°C to 125°C)

 Minimum: mean - 3s (-40°C to 125°C)
</tr

FIGURE 16-14: TYPICAL IDD vs. FREQUENCY (WDT DISABLED, RC MODE @ 300 PF, 25°C)

FIGURE 16-15: MAXIMUM IDD vs. FREQUENCY (WDT DISABLED, RC MODE @ 300 PF, -40°C to +85°C)



17.2 DC Characteristics: PIC16C54C/C55A/C56A/C57C/C58B-04E, 20E (Extended) PIC16CR54C/CR56A/CR57C/CR58B-04E, 20E (Extended)

PIC16C54C/C55A/C56A/C57C/C58B-04E, 20E PIC16CR54C/CR56A/CR57C/CR58B-04E, 20E (Extended)			Standard Operating Conditions (unless otherwise specified)Operating Temperature $-40^{\circ}C \le TA \le +125^{\circ}C$ for extended					
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions	
D001	Vdd	Supply Voltage	3.0 4.5		5.5 5.5		RC, XT, LP, and HS mode from 0 - 10 MHz from 10 - 20 MHz	
D002	Vdr	RAM Data Retention Voltage ⁽¹⁾	—	1.5*	—	V	Device in SLEEP mode	
D003	VPOR	VDD start voltage to ensure Power-on Reset	—	Vss	—	V	See Section 5.1 for details on Power-on Reset	
D004	SVDD	VDD rise rate to ensure Power-on Reset	0.05*	—	—	V/ms	See Section 5.1 for details on Power-on Reset	
D010	IDD	Supply Current ⁽²⁾ XT and RC ⁽³⁾ modes HS mode	_	1.8 9.0	3.3 20	mA mA	Fosc = 4.0 MHz, VDD = 5.5V Fosc = 20 MHz, VDD = 5.5V	
D020	IPD	Power-down Current ⁽²⁾		0.3 10 12 4.8 18 26	17 50* 60* 31* 68* 90*	μΑ μΑ μΑ μΑ μΑ μΑ	VDD = 3.0V, WDT disabled VDD = 4.5V, WDT disabled VDD = 5.5V, WDT disabled VDD = 3.0V, WDT enabled VDD = 4.5V, WDT enabled VDD = 5.5V, WDT enabled	

These parameters are characterized but not tested.

† Data in "Typ" column is at 5V, 25°C, unless otherwise stated. These parameters are for design guidance only, and are not tested.

- Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
 - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern, and temperature also have an impact on the current consumption.
 - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, TOCKI = VDD, MCLR = VDD; WDT enabled/ disabled as specified.
 - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
 - **3:** Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in kΩ.

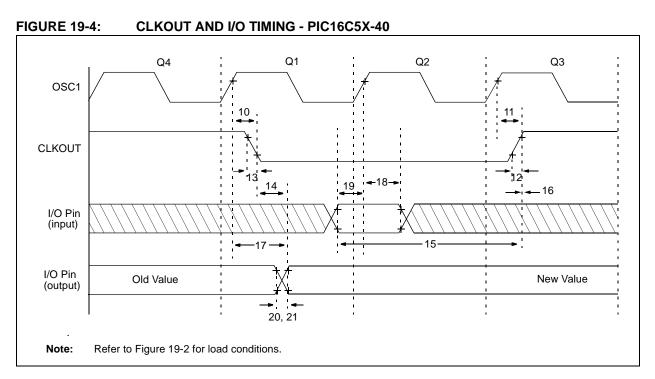


TABLE 19-2:	CLKOUT AND I/O TIMING REQUIREMENTS - PIC16C5X-40

AC Characteristics		Standard Operating Conditions (unless otherwise specified)Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial							
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units			
10	TosH2ckL	OSC1↑ to CLKOUT↓ ^(1,2)	—	15	30**	ns			
11	TosH2ckH	OSC1↑ to CLKOUT↑ ^(1,2)	—	15	30**	ns			
12	TckR	CLKOUT rise time ^(1,2)	—	5.0	15**	ns			
13	TckF	CLKOUT fall time ^(1,2)	—	5.0	15**	ns			
14	TckL2ioV	CLKOUT↓ to Port out valid ^(1,2)	—	—	40**	ns			
15	TioV2ckH	Port in valid before CLKOUT ^(1,2)	0.25 TCY+30*	—	_	ns			
16	TckH2iol	Port in hold after CLKOUT ^(1,2)	0*	—	_	ns			
17	TosH2ioV	OSC1 [↑] (Q1 cycle) to Port out valid ⁽²⁾	—	—	100	ns			
18	TosH2iol	OSC1 [↑] (Q2 cycle) to Port input invalid (I/O in hold time)	TBD	—	—	ns			
19	TioV2osH	Port input valid to OSC1↑ (I/O in setup time)	TBD	—	—	ns			
20	TioR	Port output rise time ⁽²⁾	—	10	25**	ns			
21	TioF	Port output fall time ⁽²⁾	—	10	25**	ns			

* These parameters are characterized but not tested.

- ** These parameters are design targets and are not tested. No characterization data available at this time.
- † Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: Measurements are taken in RC Mode where CLKOUT output is 4 x Tosc.

2: Refer to Figure 19-2 for load conditions.

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